

'The strong interaction at the frontier of knowledge: fundamental research and applications'

WP27

JRA9-TRACKING AND IONS IDENTIFICATIONS WITH MINIMAL MATERIAL BUDGET

Eleuterio Spiriti

INFN (National Institute of Nuclear Physics) - LNF (Frascati National Laboratory)

STRONG-2020 Kick-off meeting October 23-25, 2019

TIIMM (JRA9 - Tracking and Ions Identifications with Minimal Material budget)

"Objectives: The JRA we propose concentrate in a technological innovation in the field of tracking detectors for experiments in the hadron physics area like the ALICE project at CERN, it is also easy to envisage possible applications in the more general area of LHC particle physics experiments and in the low energy range ion tracking and identification needed in the patient particle treatment in medical physics. Common needs to those applications is to combine at the same time a precision tracking with energy loss measurement to be used for particle identification, and very low level of crossed material to minimize multiple scattering. This should include also the easiness of the data readout produced by the sensor to cope with the specific need of all the different applications."

(From STRONG2020 proposal)



- 1. Objectives
- 2. Tasks description
- 3. Update on progress
- 4. JRA9-WP27 **Deliverables**
- 5. JRA9-WP27 Milestones
- 6. Conclusion



JRA9 (TIIMM) objectives: main goal

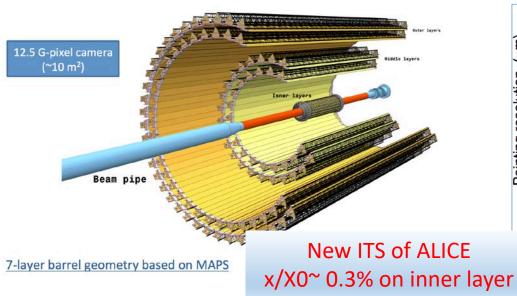
Precision
Tracking
(few µm obtained)

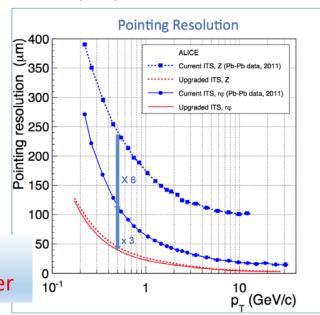


Low material Budget ($0.3 \% X_0$ achieved)



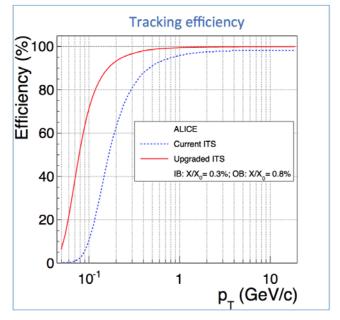
Energy loss
measurement
(still missing on large area)





Impact parameter resolution

Tracking efficiency (ITS standalone)



STR®NG-2:20

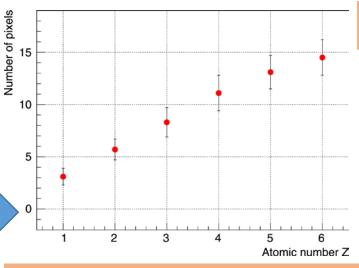
JRA9 (TIIMM) objectives

dE/dx in existing MAPS: where do we stand.

FIRST (Fragmentation of Ions for Space and Therapy)

KONNE RAJIS

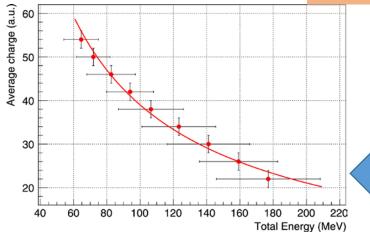
Number of pixel per cluster vs ion atomic number in FIRST data taking at GSI. Measured in the MAPS (M26) vertex detector.



M. Toppi et al., "Measurement of fragmentation cross sections of C ions on a thin gold target with the FIRST apparatus," Phys. Rev. C, vol. 93, no. 6, p. 064601, 2016.



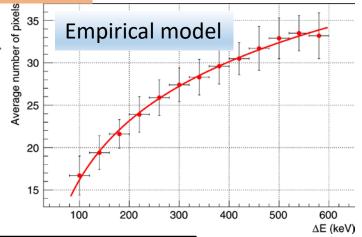
E. Spiriti et al., "CMOS active pixel sensors response to low energy light ions"; Nuclear Inst. and Methods in Physics Research, A 875C (2017) pp. 35-40



$$n_p = \frac{\pi r_T^2}{p^2} = 2\pi r_s \text{Log}\left(\frac{\Delta E}{2\pi E_g T_s}\right)$$

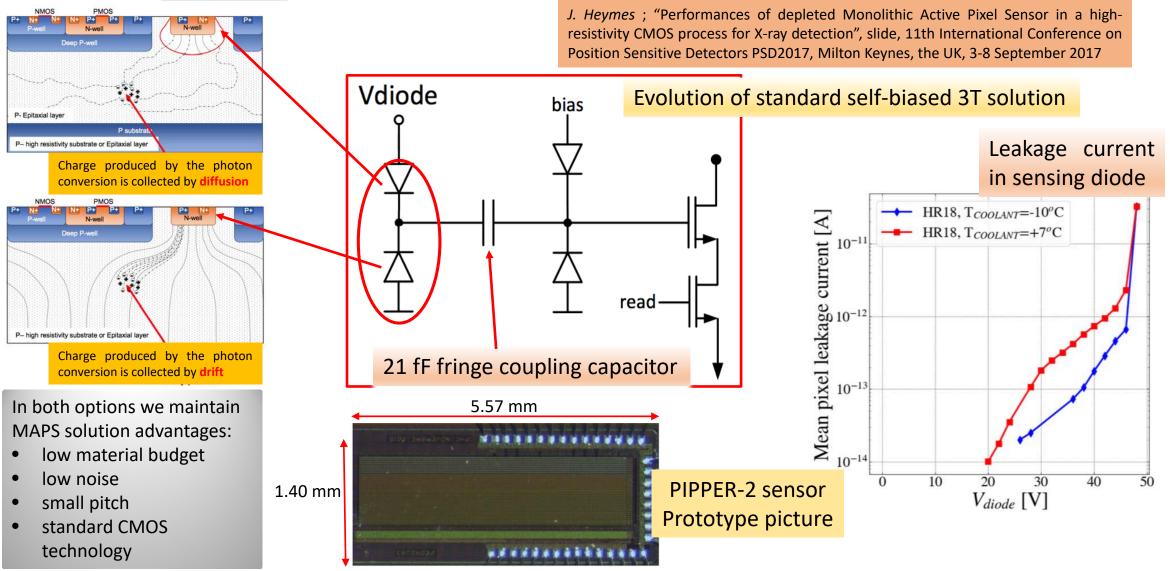
 $r_s = \sigma^2/p^2$ and $T_s = T\sigma^2$ (only two parameters) σ = spread of Gaussian charge diffusion, T = single pixel charge threshold

Measured (M18 sensor) released charge in 14 μ m thick silicon epitaxial layer vs total ion (Z=2) energy (measured in CsI telescope).





JRA9 (TIIMM) objectives: fully depleted MAPS

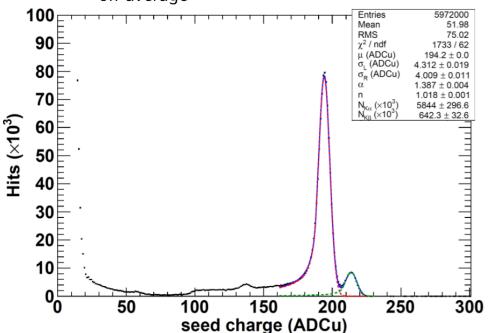




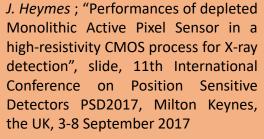
JRA9 (TIIMM) objectives: fully depletion results

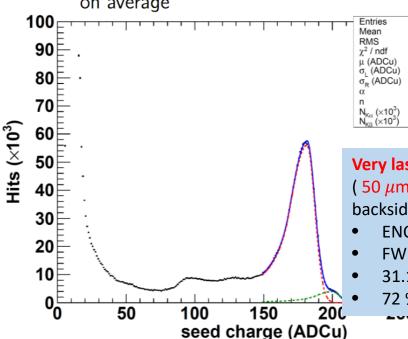
After clustering → Seed pixel charge distribution

- 18 μm thick epitaxial layer (HR18)
 - \square ENC = 24 e⁻
 - ☐ FWHM (5.9 keV) = 298 eV
 - □ 30.38 eV/ADCu
 - ☐ Si escape peak visible (138 ADCu)
 - ☐ 75 % of the charges collected on the seed pixel on average



- 280 μm thick Czochralski (CZ)
 - \square ENC = 26 e⁻
 - ☐ FWHM (5.9 keV) = 686 eV
 - ☐ 32.51 eV/ADCu
 - \square Mn-K α and Mn-K β merging
 - □ 68 % of the charges collected on the seed pixel on average





Very last news (preliminar)!

8012643

769.4 / 57

 12.3 ± 0.7

 1863 ± 56.4 132 ± 4.2

 181.5 ± 0.0

59.03

69.97

($50 \mu m$ thick, CZ silicon,

backside processed, 30V bias)

- ENC unchanged
- FWHM = = 350 eV
- 31.1 eV/ADCu
- 72 % of charge on seed pixel

Pipper-2 measurements (presc. 2, T°_{cool}=7 °C, V_{diode}=30V) ⁵⁵Fe irradiation – 400000 frames



This project has received funding from the European Union's Horizon 2020 research and innovation programme under grant agreement No 824093.

JRA9 (TIIMM) objectives

Which relevant innovations we target in the TIIMM project?

A proof of principle device integrating the MAPS good tracking performancies with the dE/dx measurements capabilities on large area sensors.

Still a lot of open questions:

- Analog or digital output?
- Power consumption?
- Pixel pitch (single point resolution)?
- In pixel discriminator?
- In pixel Analog to Digital Conversion (pipeline ADC)?
- Integration time?
- Sparse or full frame readout? (application dependen
-

Which characteristics for the final instrument TIIMM is aimimg?

Incorporate as much as possible the functionalities existing in the hybrid sensors (Timepix3?!?!?!?!).

Most of the trade off choices are strongly dependent on the final application.

TIIMM goal zero: deliver a prototype to establish the feasibility at a large sensor scale size.

Common goal with TIIMM

Example of similar questions in the MIMOSIS project for CBM

Pixel diode: Add HV front biasing (More rad. hardness due to higher HV, suppress back bias effects on NMOS transistors).

Priority encoder: Optimize layout, accelerate by factor 2x.

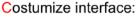
Eliminate bonding pads in pixel area (reduce integration challenge).

Collection electorde ELT transistors if needed.

Preamp: Understand ionizing radiation effects, add

Preamp: Increase power, reduce noise, speed-up.

> Pixel memory: Simplify (increase robustness to SEU).



- Higher bandwidth
- Higher power /robustness
- Compatibility with GBTx

STRONG 2:20

This project has received funding from the European Union's Horizon 2020 research and innovation programme under grant agreement No 824093.

JRA9 (TIIMM) update on progress: fully depleted MAPS update!

Fully depleted MAPS – small electrodes with TJ modified process



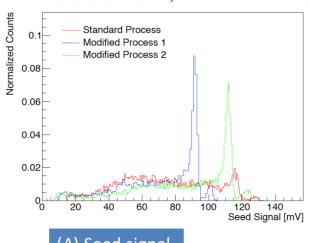
Signal and cluster distribution from a ⁵⁵Fe source for standard and modified process

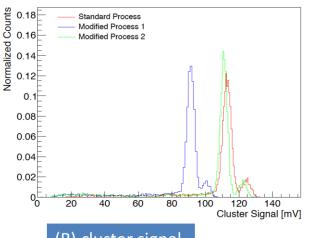
Modified Process 1 = higher dose, Modified Process = lower dose

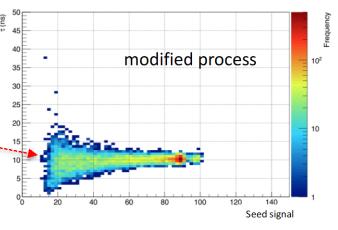
J. Van Hoorne et al., NSS 2016

Tests performed on investigator chip (same pixel as ALPIDE)

Pixel size: 28 x 28 ∞m², CE: 2 x 2 ∞m² centered in a 8 x 8 ∞m² opening, P-well & substrate @ -6V, CE @ 1V







(A) Seed signal

(B) cluster signal

Note: chip output buffer limits the rise time to 10ns

- For a lower dose (MP1) a no sensor capacitance penalty
- For modified process, larger fraction of single pixel clusters (see also fraction of signal within the peak in A)

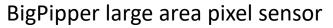
L. Musa (CERN) – VCI, Vienna, Feb 2019

← Credits to:

27

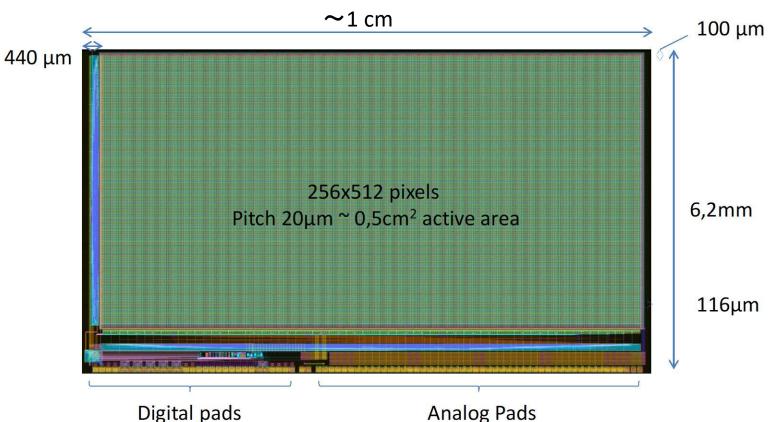


JRA9 (TIIMM) update on progress



NOT FUNDED BY STRONG2020

Tower Jazz 180nm Strasbourg group submission



Modified process

- Fully depleted
- Rolling shutter/Global shutter
- Analog output
- ROI (Region Of Interest) definition
- 20 μ m pitch

Extremely useful to characterize the charge collection versus released energy in the sensor.

Important step before prototype with ADC on chip.

JRA9 (TIIMM) update on progress



EEE JOURNAL OF SOLID-STATE CIRCUITS, VOL. 53, NO. 11, NOVEMBER 2019

A 6.9-μm Pixel-Pitch Back-Illuminated Global Shutter CMOS Image Sensor With Pixel-Parallel 14-Bit Subthreshold ADC

Masaki Sakakibara[®], Member, IEEE, Koji Ogawa, Shin Sakai, Yasuhisa Tochigi, Katsumi Honda, Hidekazu Kikuchi, Takuya Wada, Yasunobu Kamikubo, Tsukasa Miura, Masahiko Nakamizo, Naoki Jyo, Ryo Hayashibara, Shinya Miyata, Satoshi Yamamoto, Yoshiyuki Ota,

Hirotsugu Takahashi, Tadayuki Taura, Yusuke Oike[©], *Member, IEEE*, Keiji Tatani[©], Takayuki Ezaki, and Teruo Hirayama

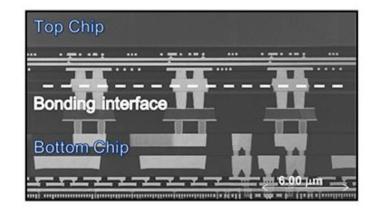


We do not even think to reach a fraction of such performances.
We don't have access to

the technology and its cost would be prohibitive

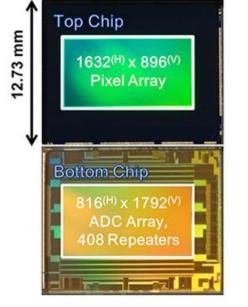
BUT we'll use it as reference

SONY Semiconductors









16.08 mm

• 6.9 μ m pitch

• 1632 x 896 pixel matrix

CIS wafer: 90 nm, 1 Poly 4 Metal

Logic wafer: 65 nm, 1 Poly 7 Metal

ADC resolution: 14 bits

• 660 fps

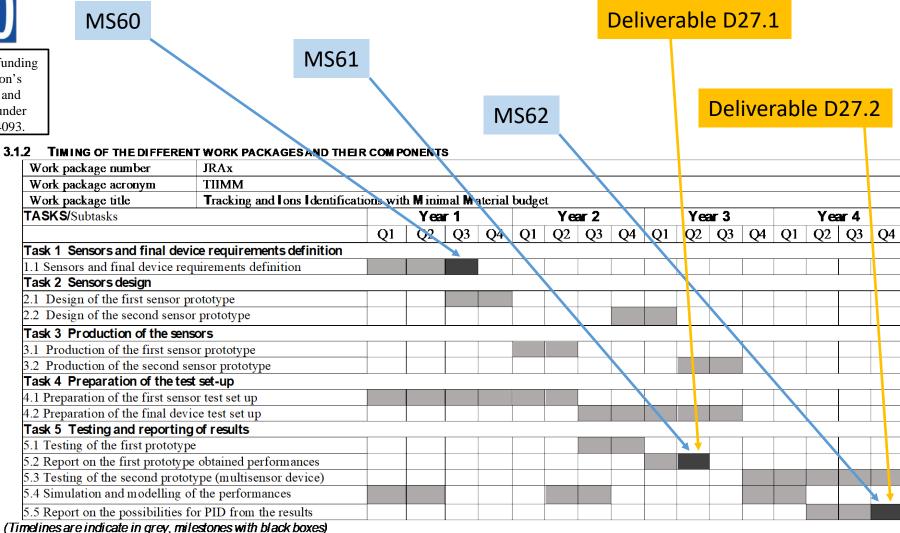
Dynamic range: 70.2 dB

Left: cross-section of the Cu-Cu connection, Upper right: pixel substrate, Lower right: logic substrate



This project has received funding from the European Union's Horizon 2020 research and innovation programme under grant agreement No 824093.

JRA9 (TIIMM) tasks structure





This project has received funding from the European Union's Horizon 2020 research and innovation programme under grant agreement No 824093.

The TIIMM team structure (expertise)

Group	Contact person	Hadron/particle Physics	Medical Physics	Detectors development
German Cancer Research Center (DKFZ), Heidelberg, Germany	Dr. Maria Martisikova			
INFN, Bari Section, Bari, Italy	Dr. Vito Manzari			
GSI Helmholtzzentrum für Schwerionenforschung, Darmstadt, Germany	Dr. Ulrich Weber			
INFN, Trento Institute for Fundamental Physics and Applications, Trento, Italy	Dr. Emanuele Scifoni			
IPHC (Institute Pluridisciplinaire Hubert Curien), In2p3, Strasbourg, France	Prof. Jerome Baudot			
LNF (Frascati National Laboratory), INFN, Frascati, Italy	Dr. Eleuterio Spiriti			



This project has received funding from the European Union's Horizon 2020 research and innovation programme under grant agreement No 824093.

JRA9 : Deliverables

There are no deliverables due for Reporting Period 1 (18 months, June 2019-November 2020)



This project has received funding from the European Union's Horizon 2020 research and innovation programme under grant agreement No 824093.

JRA9: Milestones

MS60 has to be achieved M9 (February 2020)

Milestone number ¹⁸	Milestone title	Lead beneficiary	Due Date (in months)	Means of verification
MS60	Definition of the first prototype and final device characteristics.	30 - INFN	9	Report

Advancement

MS60 on going

Expected delivery date

End of February 2020



JRA9 (TIIMM) conclusion

- The bigPipper sensor will be submitted for production in few weeks
- TCAD simulation of charge collection in "modified" process sensor started
- A student started beginning of october to study possible new architectures
- Designer of bigPipper available to contribute to the first TIIMM prototpe design
- GEANT4 simulation of charge release is under way